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Kinetics of Liquid-film Assisted Densification during Flash Sintering of Ceramic Nanoparticles

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- *Dr. Sergei Kalabukhov* *Ben-Gurion University, Israel*
- *Geoffroy Chevallier* *CIRIMAT, Toulouse, France*

Outline

- *Densification mechanisms during the Flash Sintering*
- *Formation of a liquid-film*
 - *Thermodynamics and Kinetics*
 - *Densification via liquid-film capillary forces*
 - *The lack of residual amorphous layer*
- *Summary & Conclusions*

*Densification mechanisms suggested
for Flash Sintering*

Solid-state sintering ↔ *Liquid-film assisted sintering*

Avalanche of point defects ↔ *Liquid film*

Bulk phenomenon ↔ *Surficial / Interfacial
phenomenon*

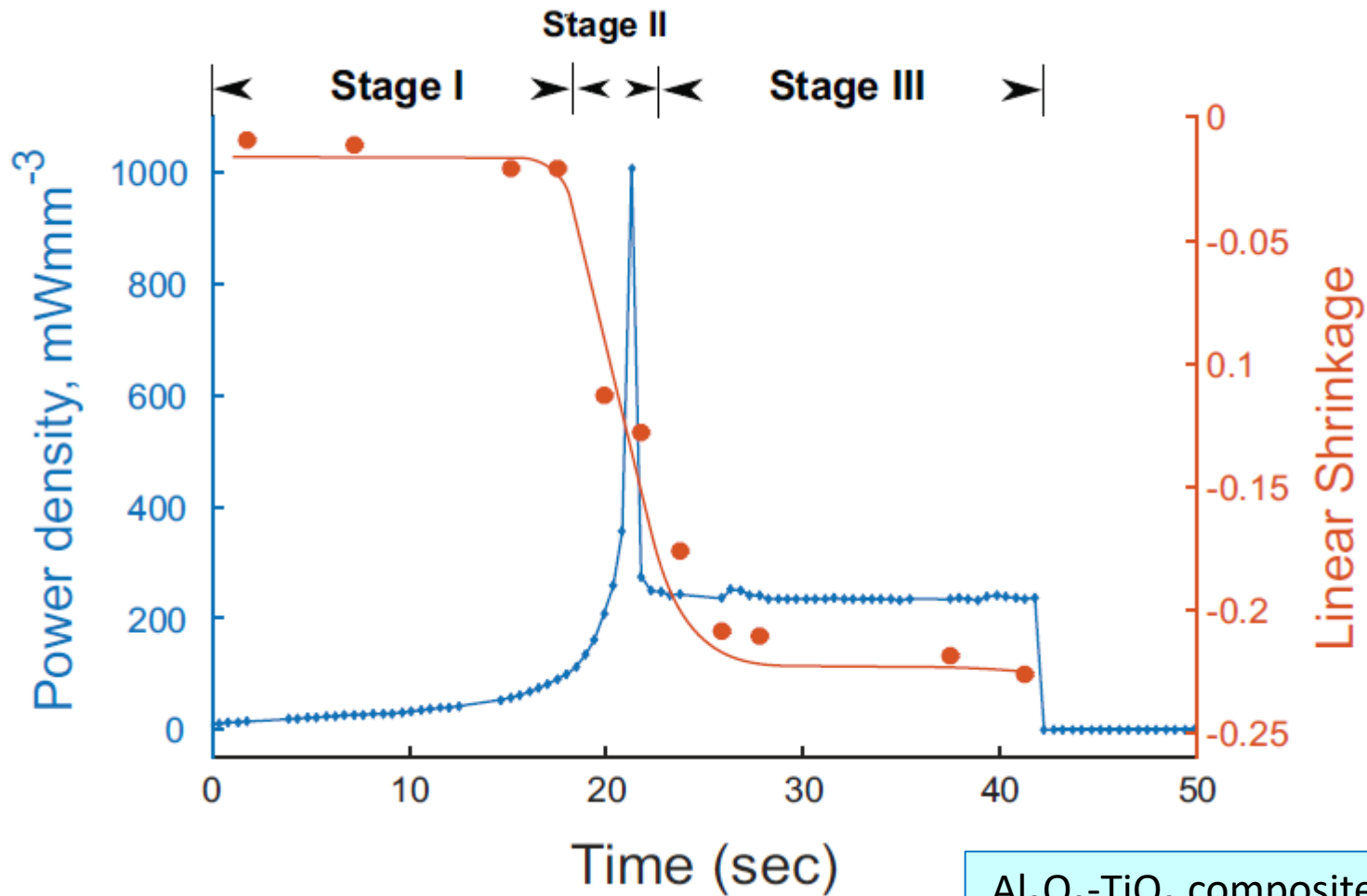
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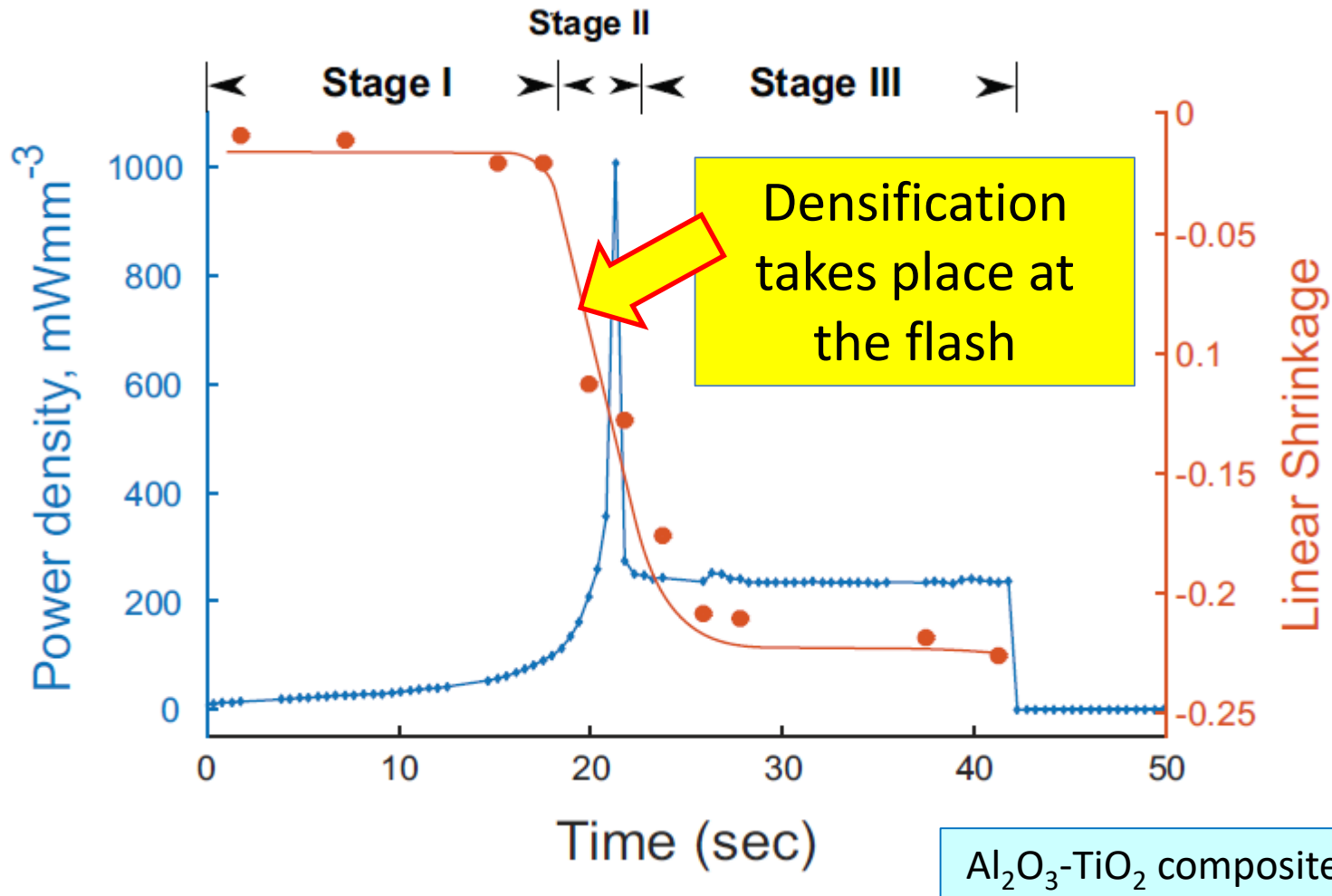
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The power peak is *Artificial*

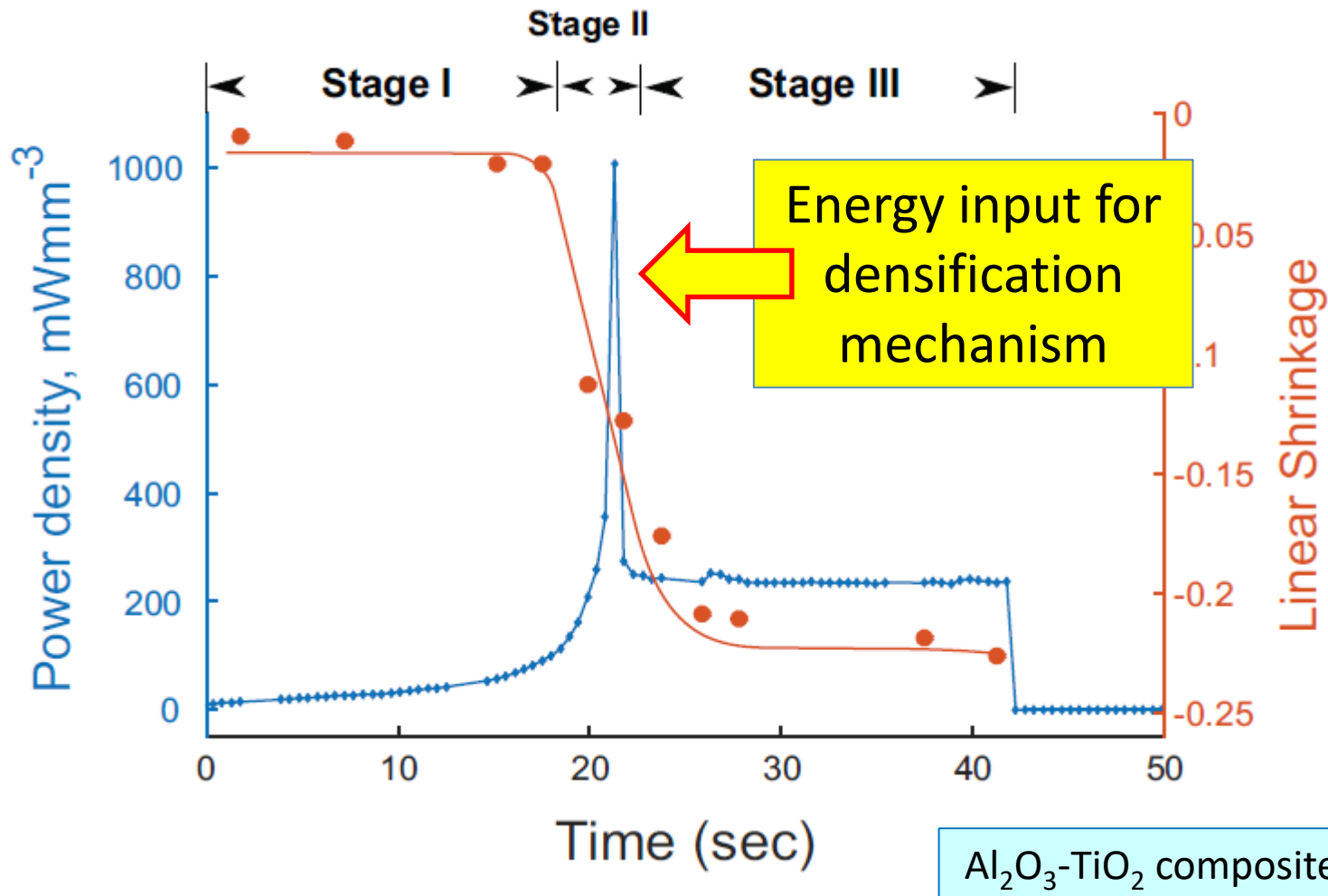


$\text{Al}_2\text{O}_3\text{-TiO}_2$ composite

The power peak is *Artificial*



The power peak is *Artificial*



Flash sintering of dielectric nanoparticles as a percolation phenomenon through a softened film

Rachman Chaim,^{1,a)} Geoffroy Chevallier,^{2,b)} Alicia Weibel,^{2,c)} and Claude Estournès^{2,d)}

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Recent work [Biesuz *et al.*, J. Appl. Phys. **120**, 145107 (2016)] showed analogies between the flash sintering and dielectric breakdown in α -aluminas pre-sintered to different densities. Here, we show that flash sintering of dielectric nanoparticles can be described as a universal behavior by the percolation model. The electrical system is composed of particles and their contact point resistances, the latter softened first due to preferred local Joule heating and thermal runaway during the flash. Local softening has a hierarchical and invasive nature and propagates between the electrodes. The flash event signals the percolation threshold by invasive nature of the softened layer at the particle surfaces. Rapid densification is associated with local particle rearrangements due to attractive capillary forces induced by the softened film at the particle contacts. Flash sintering is a critical phenomenon with a self-organizing character. The experimental electric conductivity results from flash sintering are in full agreement with those calculated from the percolation model. *Published by AIP Publishing.* [<http://dx.doi.org/10.1063/1.4980853>]

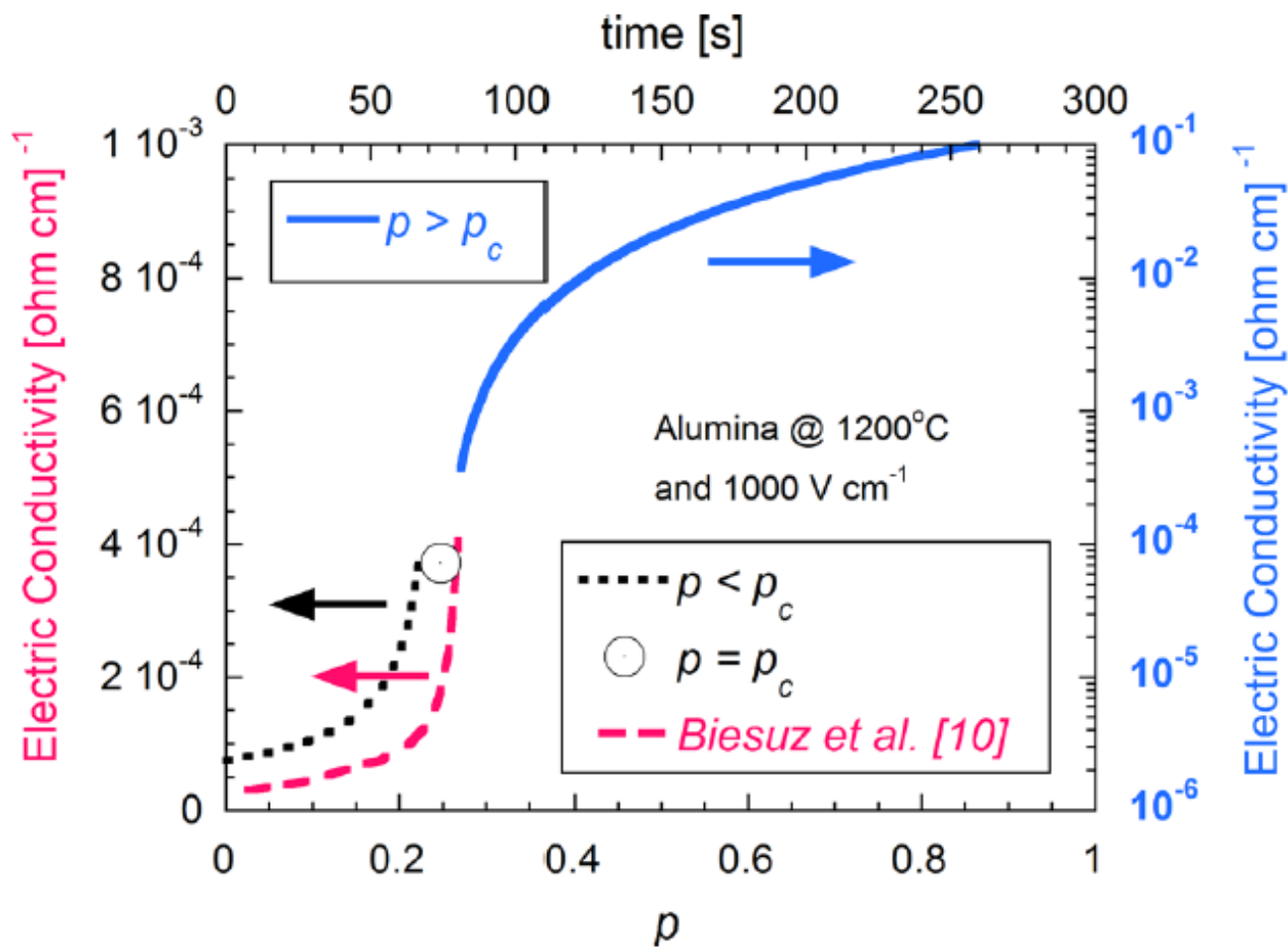


FIG. 1. Electric conductivity of α -Al₂O₃ nanoparticles subjected to flash sintering at 1200 °C under 1000 V·cm⁻¹ versus time (top x-axis) (Ref. 10), and the volume fraction of the melt p (bottom x-axis). The experimental (red dashed-curve) coincides with the calculated (dotted black-curve) from the percolation model. The flash “incubation time” of 81 s was adjusted to the percolation threshold at $p_c = 0.247$ (open circle).

*Invasion Percolation Model via **surface softening***

- 1. Joule heating at critical particle contacts → local melting.*
- 2. Incubation time is associated with the percolation threshold.*
- 3. Current percolation through the melt.*

***No current limit:** Dielectric breakdown*

***Current limit:** Current control forms local melts throughout the specimen → Particle wetting and rearrangement by capillary forces.*

On thermal runaway and local endothermic/exothermic reactions during flash sintering of ceramic nanoparticles

J Mater Sci (2018) 53:6378–6389

Rachman Chaim^{1,*}  and Claude Estournès²

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Theory

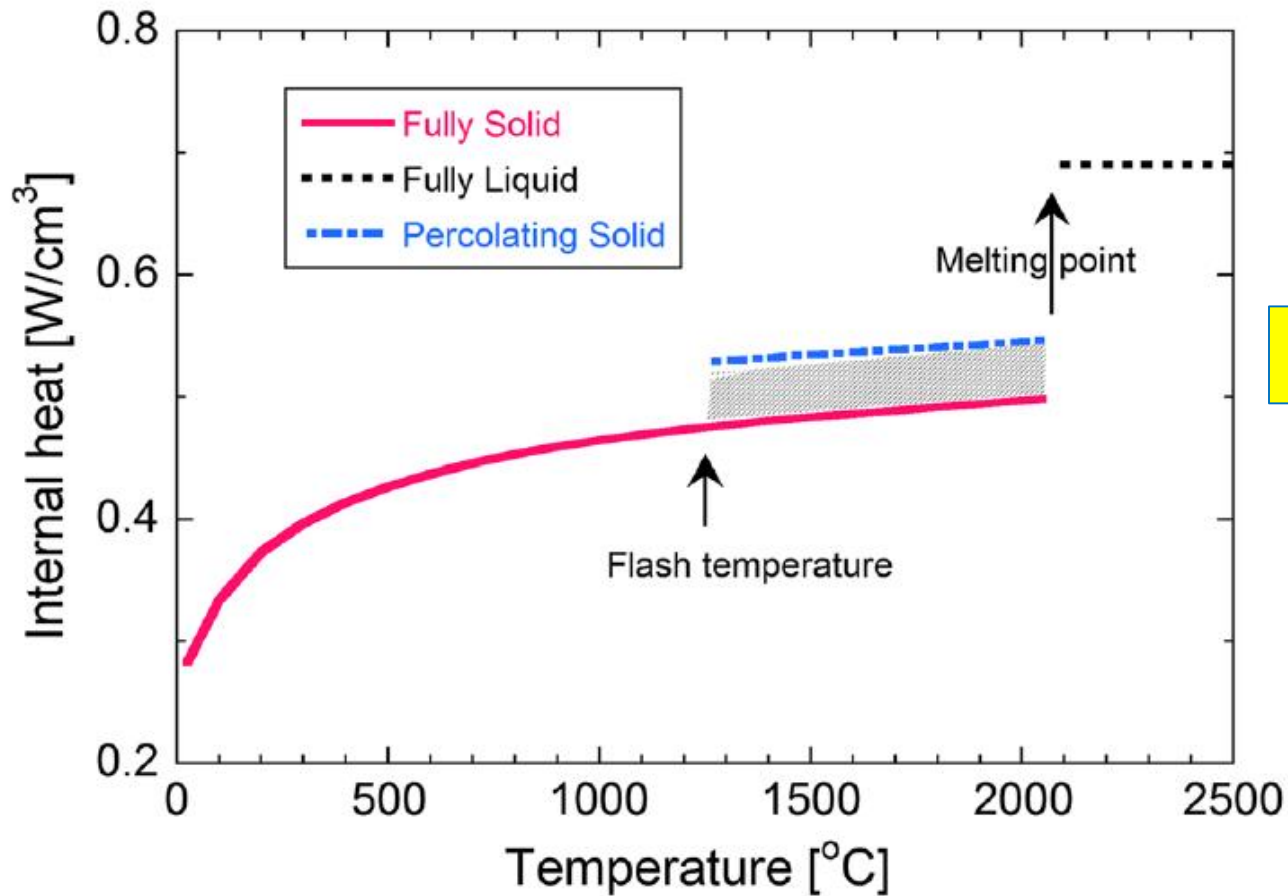
Heat transfer from nanoparticles

Conduction heat transfer

Radiation heat transfer

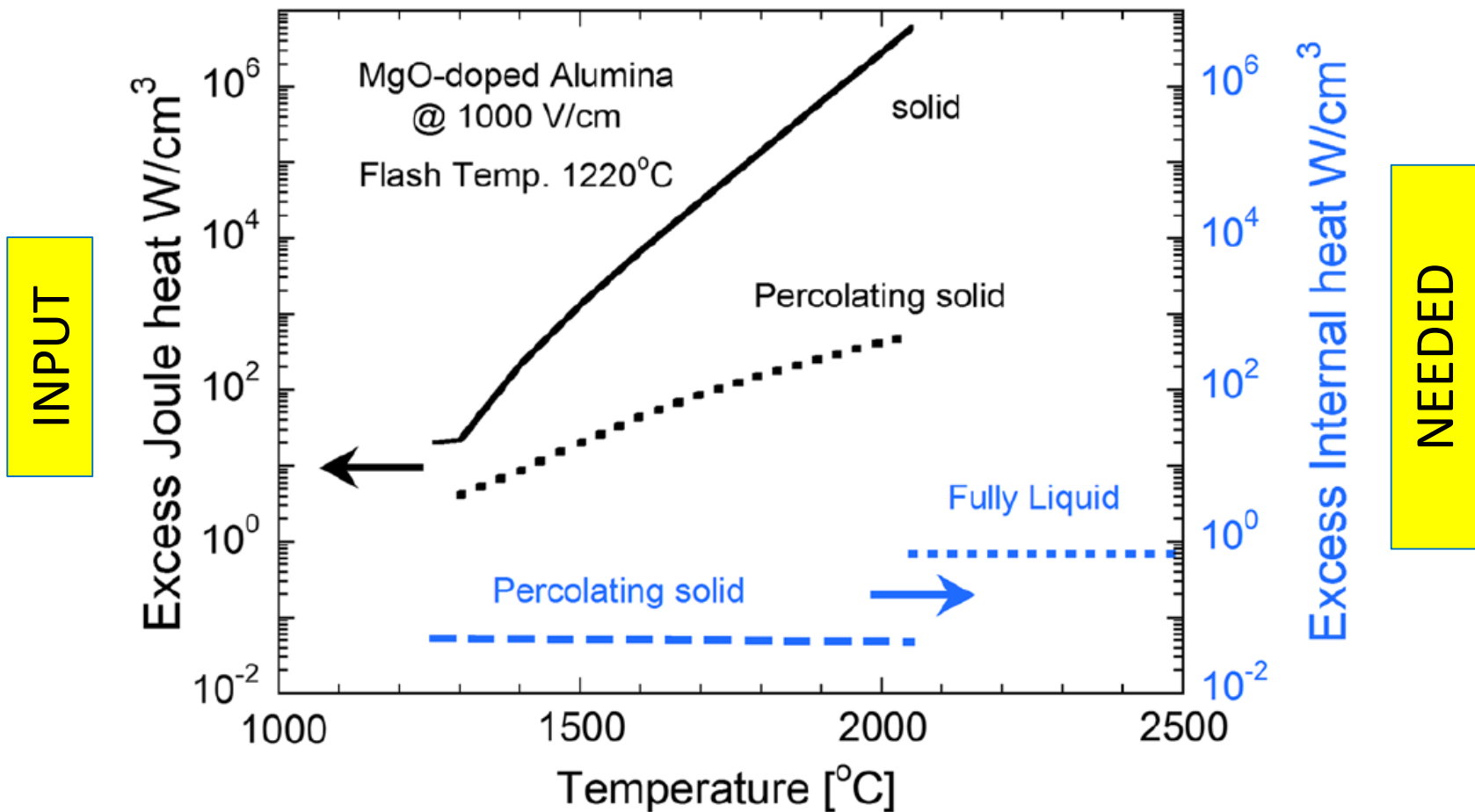
Heat balance at flash event

Thermodynamics of Liquid-film formation

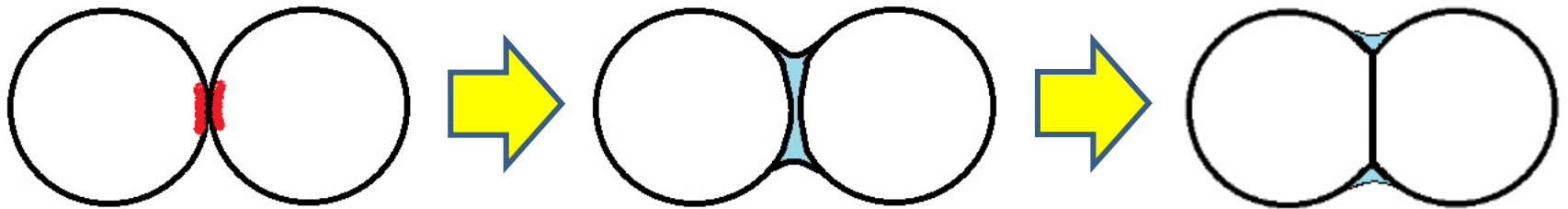


Alumina

Thermodynamics of Liquid-film formation



Densification during Flash Sintering by *Liquid-film Capillary*



| | | | | | |
|-----------------------------|----|-----|-----|-----|-----------------|
| Particle diameter [nm] | 50 | 100 | 200 | 500 | 1 μm |
| Capillary pressure [MPa] | 56 | 28 | 14 | 5.6 | 2.8 |

Hot Press Values

Regular Article

On the kinetics of liquid-assisted densification during flash sintering of ceramic nanoparticles

Rachman Chaim

Scripta Materialia 158 (2019) 88–90

Department of Materials Science and Engineering, Technion – Israel Institute of Technology, Haifa 32000, Israel



A R T I C L E I N F O

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Liquid-film assisted Sintering

The *capillary force* in the presence of liquid is *equivalent to externally applied pressure* of:

$$P_{ext} = 2\pi\sqrt{2} \cdot \frac{\gamma_{lv}}{r_p} \cos \theta$$

γ_{lv} - liquid-vapor surface energy

r_p - particle radius

θ - wetting angle

Liquid-film Sintering *Kinetics*

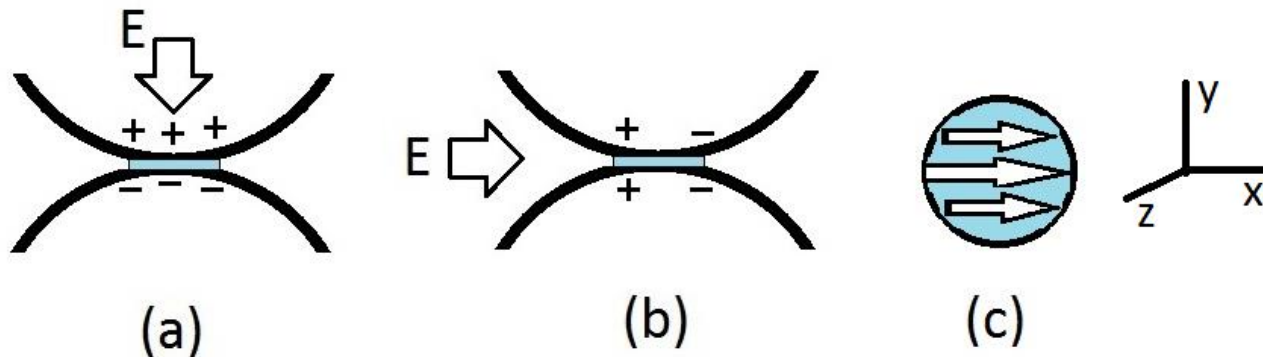
The main question is:

Are the kinetics of these processes *fast enough to fulfill a few seconds* durations of the flash sintering process.

Therefore, our main target is *to evaluate the time scale* of the *wetting* and *rearrangement processes* using the *existing models*.

Electro-osmotic / Capillary liquid flow

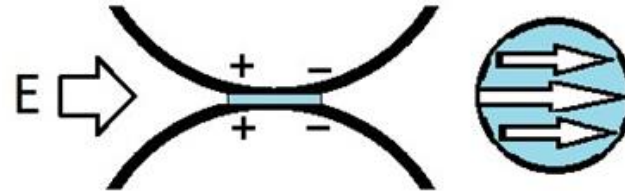
- We checked the *electro-osmotic forces and velocities* and *capillary forces and velocities*.
- For electric fields *perpendicular* and *parallel* to the liquid at the contact.
- For *jammed particles* and *free-to-move particles*.



Electro-osmotic liquid flow

- The *terminal velocity, V* of the molecule (cation with two anions) in the liquid film at the particle contact subjected to external electric field *parallel to the film* is:

$$V = \frac{Z \cdot e E}{4\pi a}$$



Z - cation valence electrons

e - electron charge

E - electric field

η - viscosity of the liquid

a - average molecule radius

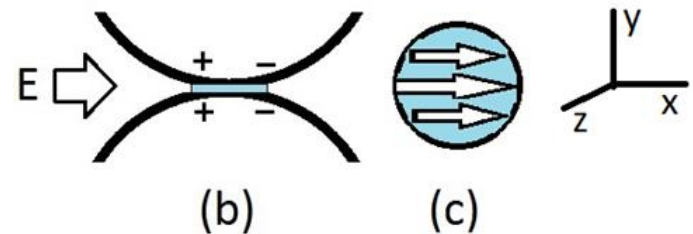
Electro-osmotic liquid flow

- *The flow speed of the anionic polyhedra under the electric field at the edges of the liquid film and against the drag by the positive ions at the double-layer.*

MgO-doped Al_2O_3 @ 1000 V/cm

Al_2O_3 melt: $Z = 3$, $a = 0.319$ nm

Viscosity of 0.044 [Pa·s] at 2323K

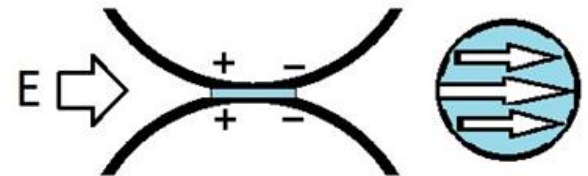


Terminal velocity: $272 \mu\text{m}\cdot\text{s}^{-1}$

Electro-osmotic liquid flow

- *The directional symmetry of the electric field imposes directional flow in the field direction (**Posieuille flow**).*
- *If one particle is free of geometrical constraints, the viscous drag may shear it from its neighbor (**Couette flow**).*

Particle rearrangement is accelerated by particle sliding and rotation assisted by the electro-osmotic flow.



Capillary driven liquid flow

- *Superposition of the acting forces to highlight the effect of the capillary forces on the flow of the Liquid-film.*
- *The liquid at the contact leads to capillary forces that are balanced by the viscous drag.*
- *We assumed that the melt at the contact flows radially between the two particles.*

Capillary driven liquid flow

- Following the velocity profile between two fixed and parallel disc surfaces (*Posieuille flow*).
- The *maximum radial flow rate* of the liquid due to pressure gradient ΔP expressed as:

$$u_{max} = \frac{\Delta P (\delta_b)^2}{2 r \ln \left(\frac{r_2}{r_1} \right)}$$

δ_b is the liquid film thickness,
 η is the liquid viscosity

r is the radial distance somewhere between r_1 (disc center) and r_2 (disc perimeter) where the *external* pressure gradient exist

The case of particle neck wetting

- *The driving force for wetting is the internal capillary force due to the curvatures at the liquid meniscus.*
- *The pressure gradient is:*

$$\Delta P = \gamma_{lv} \left(\frac{1}{r_2} - \frac{2}{\delta_b} \right)$$

γ_{lv} is the liquid-vapor surface energy

r_2 is the contact radius

Two curvatures with positive and negative signs

The *Maximum* flow velocity

- The maximum flow velocity at the film perimeter, r_2 , is:

$$u_{max} = \gamma_{lv} \left(\frac{1}{r_2} - \frac{2}{\delta} \right) \frac{(\delta_b)^2}{2 r_2 \ln \left(\frac{r_2}{r_1} \right)}$$

The above equations based on the *steady state flow* conditions. Nevertheless, we are interested in *the liquid flow at the early stages of the wetting* hence, our calculations may be estimates.

The *Maximum* flow velocity

- *Example:* MgO-doped Al₂O₃
- $r_p = 50 \text{ nm}$, $\gamma_{lv} = 0.7 \text{ J}\cdot\text{m}^{-2}$
- Liquid film thickness of $\delta_b = 1.5 \text{ nm}$
- Assuming a dry neck to particle radius ratio 0.02 in the green compact, hence $r_1 = 0.02 \cdot r_p$

*Wetted neck to particle radius ratio of 0.10 and 0.20
that correspond to neck radii of 5 nm and 10 nm*

Maximum flow velocities of 1.04 m·s⁻¹ and 0.48 m·s⁻¹

The *Maximum* flow velocity

- *These extremely high velocities indicate that liquid flow is instantaneous (i.e. from the time of its formation at the neck center) hence the neck is fully wet and the liquid reaches the neck meniscus within **tens of nanoseconds**.*
- *Comparison of the ion velocities in the melt:*

Capillary force effect >> Electric field effect

Is there any *residual amorphous phase*?

- *Solidification of the melt by epitaxial (heterogeneous) nucleation*
- *Most favorable on its counterpart solid substrate.*
- *The nucleation energy barrier needed for such a critical nucleus:*

$$\Delta G_{het}^* = \frac{16 \pi (\gamma_{sl})^3}{3 (\Delta G_v)^2} S(\theta)$$

γ_{sl} - *solid-liquid specific interface energy*

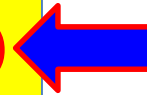
ΔG_v - *free energy change per unit volume due to the nucleus*

$S(\theta)$ - *nucleus shape factor that depends on the contact angle θ*

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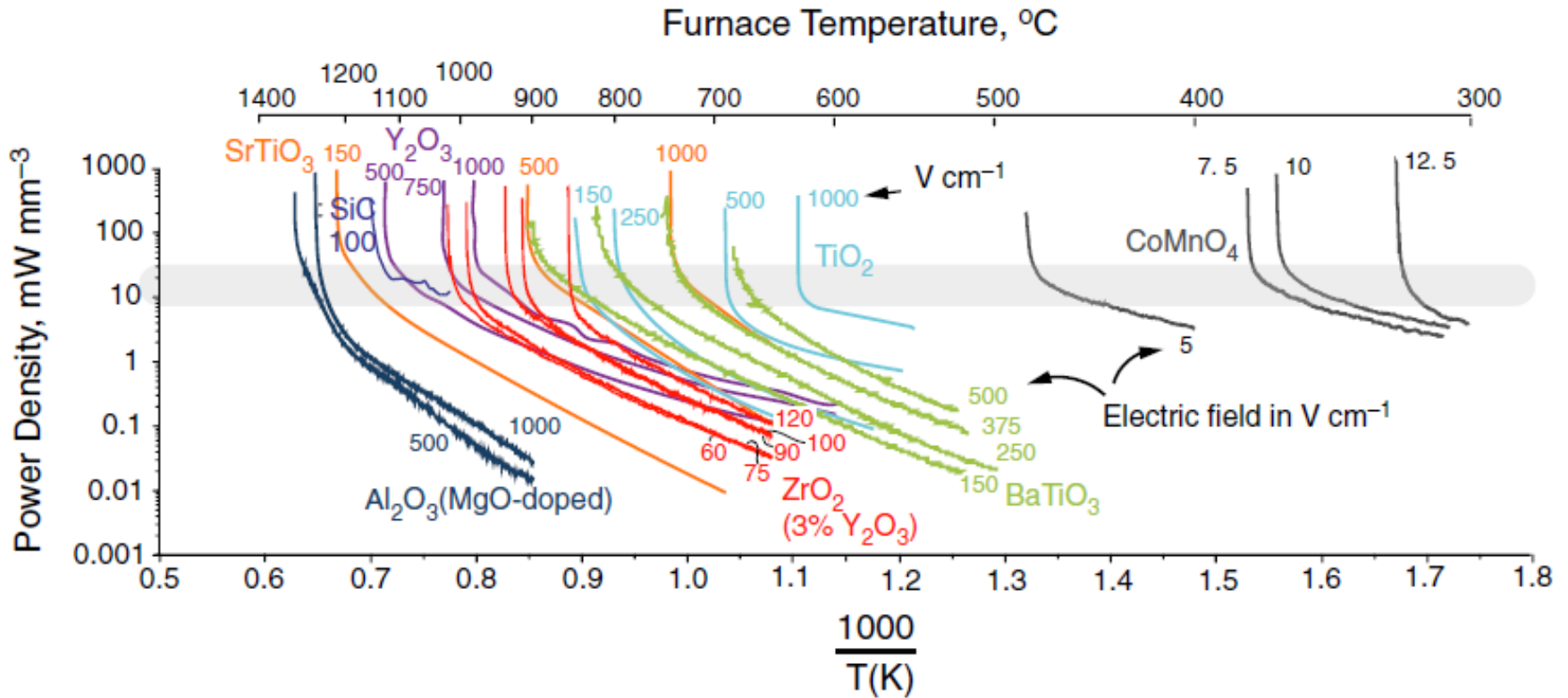


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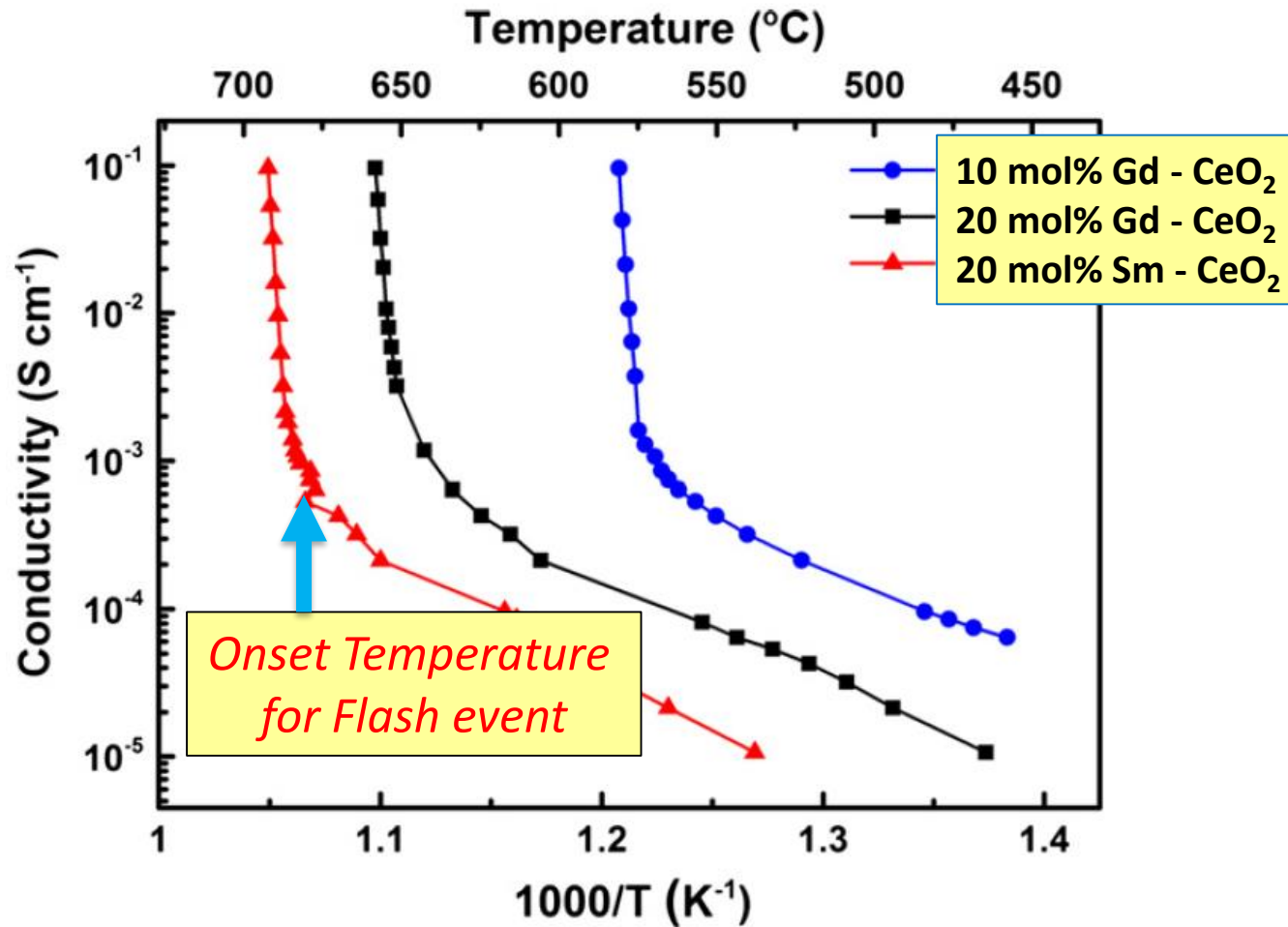
ΔG_v - *free energy change per unit volume due to the nucleus*

$S(\theta)$ - *nucleus shape factor that depends on the contact angle θ*


Sudden & drastic increase in *dissipated Power*



Conductivity increase vs. furnace temperature



Numerical model for particle size effects on flash sintering temperature of ionic nanoparticles

Rachman Chaim^{1,*} 

J Mater Sci (2018) 53:13853–13864

¹Department of Materials Science and Engineering, Technion – Israel Institute of Technology, 32000 Haifa, Israel

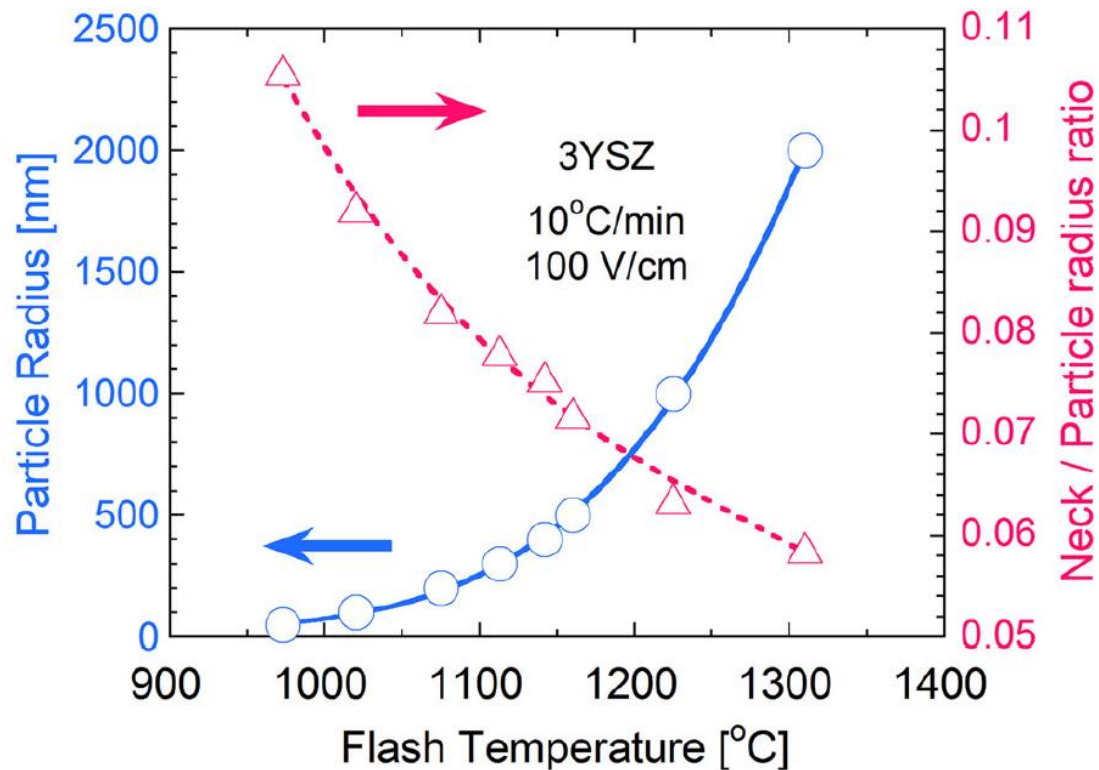


Figure 6 Calculated flash temperature versus particle radius and neck to particle radius ratio in 3YSZ in the particle size range of 50–2000 nm.

Effects of the fundamental oxide properties on the electric field-flash temperature during flash sintering

Rachman Chaim^{a,*}, Claude Estournès^b

Scripta Materialia 163 (2019) 130–132

^a Department of Materials Science and Engineering, Technion – Israel Institute of Technology, Haifa 32000, Israel

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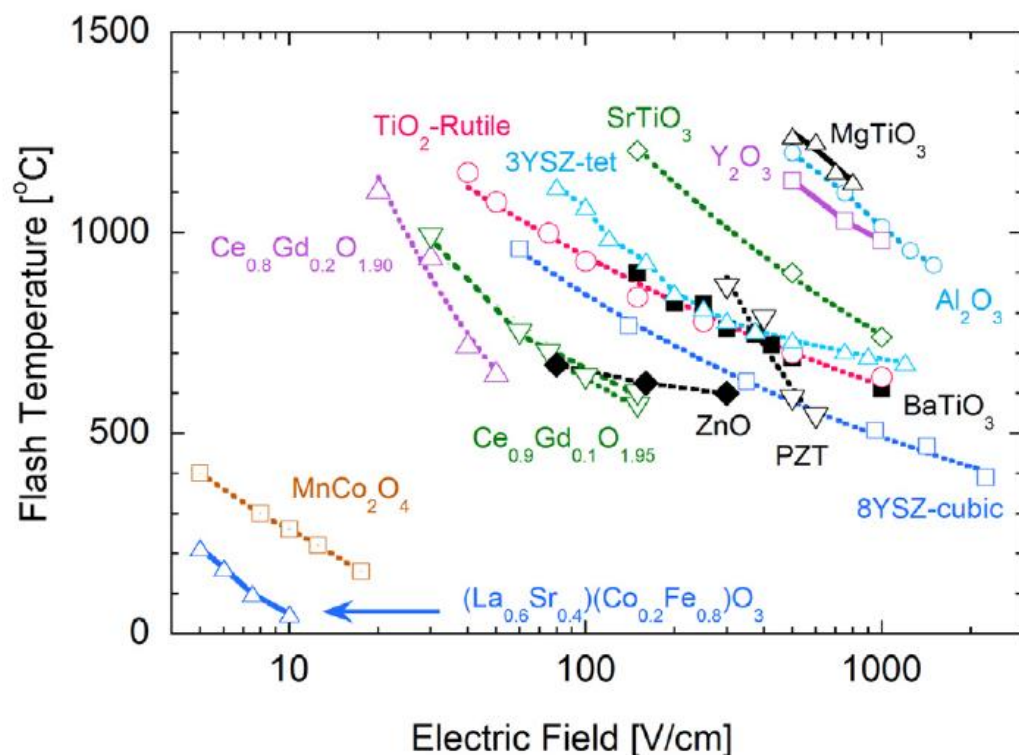
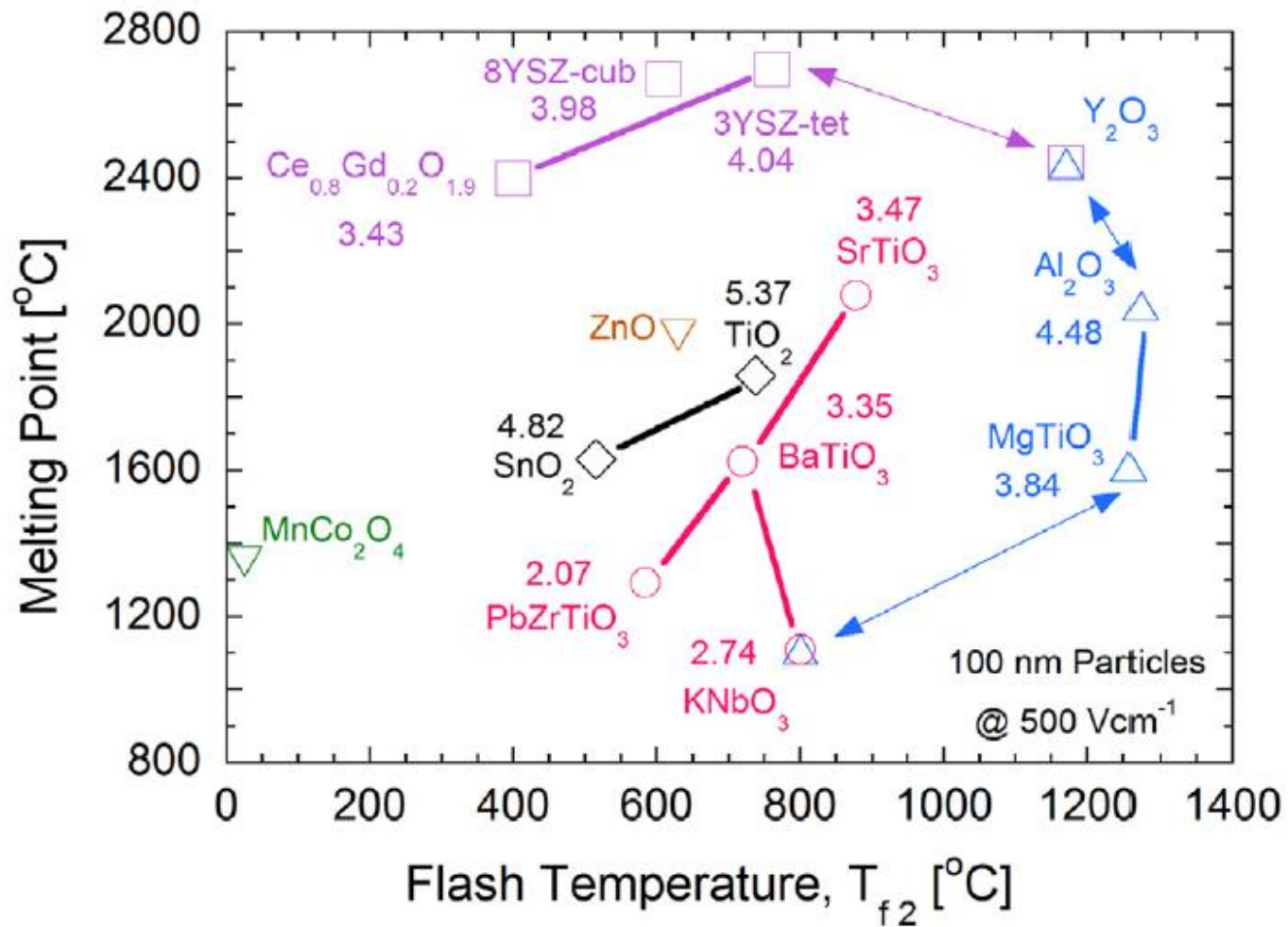


Fig. 1. Experimental flash temperature–electric field relations in different oxides: Al_2O_3 [1], BaTiO_3 [10], $\text{Ce}_{0.9}\text{Gd}_{0.1}\text{O}_{1.95}$ [11,12], $\text{Ce}_{0.8}\text{Gd}_{0.2}\text{O}_{1.90}$ [13], $(\text{La}_{0.6}\text{Sr}_{0.4})(\text{Co}_{0.2}\text{Fe}_{0.8})\text{O}_3$ [12], MgTiO_3 [16], MnCo_2O_4 [17], $\text{Pb}(\text{Zr}_{0.52}\text{Ti}_{0.48})\text{O}_3$ – PZT [18], SrTiO_3 [20], TiO_2 [21], Y_2O_3 [22], 3YSZ [23], 8YSZ [24], and ZnO [25].



the 'structure-field maps' of Goldschmidt

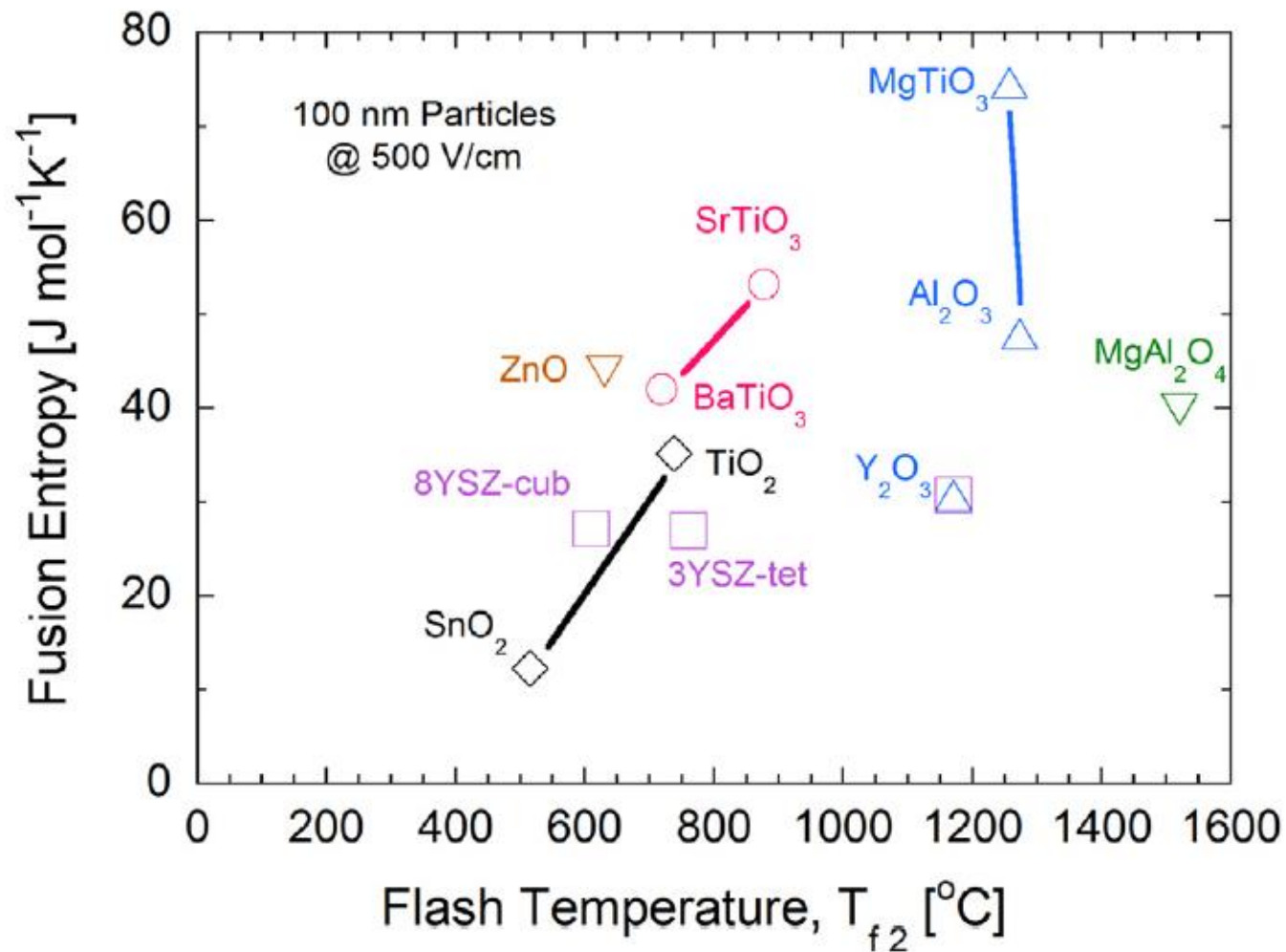


Fig. 3. Fusion entropy–flash temperature diagram of oxides normalized for the 100 nm particle size under the $500 \text{ V} \cdot \text{cm}^{-1}$ electric field. The lines used as guidelines only to highlight the oxides with similar crystal structure.

Summary & Conclusions

- *The kinetics of flash sintering assisted by a liquid-film is in agreement with the experimental time scales of a few seconds.*
- *Joule heat provides the activation energy for **local surface softening / melting**.*
- *Thermal runaway is an **endothermic local melting** of the particle contacts. The **transient liquid** solidifies after the particle rearrangement.*

Summary & Conclusions

- *Homologous crystallization* of the local melt after particle rearrangement is *energetically preferred* due to the exothermic nature of solidification.

Thank you for your attention

